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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
AT LIGHTION NO.	112.110 27.112	THE THURS HAVE COLOR	ATTORNES DOCKES NO.	CONTINUENTION NO.
10/610,498	06/30/2003	Francis G. Celii	T1-34580	5368
23494 75	590 03/14/2006	EXAMINER		
	RUMENTS INCOR	DEO, DUY VU NGUYEN		
	P O BOX 655474, M/S 3999 DALLAS, TX 75265		ART UNIT	PAPER NUMBER
			1765	

DATE MAILED: 03/14/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)
		10/610,498	CELII ET AL.
	Office Action Summary	Examiner	Art Unit
		DuyVu n. Deo	1765
Period fo	- The MAILING DATE of this communication app r Reply	ears on the cover sheet with the o	correspondence address
A SHO WHIC - Exten after S - If NO - Failur Any re	DRTENED STATUTORY PERIOD FOR REPLY HEVER IS LONGER, FROM THE MAILING DO SIGNED STATUTORY PERIOD FOR REPLY SIGNED STATES AND A THE MAILING DO SIGNED STATES AND A	ATE OF THIS COMMUNICATION  36(a). In no event, however, may a reply be ting  will apply and will expire SIX (6) MONTHS from  a cause the application to become ABANDONE	N. nely filed the mailing date of this communication. (D) (35 U.S.C. § 133).
Status			
2a)⊠ 3)□	Responsive to communication(s) filed on 10 Ja This action is <b>FINAL</b> . 2b) This Since this application is in condition for allowar closed in accordance with the practice under E	action is non-final.  nce except for formal matters, pro	
Dispositi	on of Claims		
5)□ 6)⊠ 7)□ 8)□	Claim(s) 3-7 and 9-13 is/are pending in the apple 4a) Of the above claim(s) is/are withdraw Claim(s) is/are allowed. Claim(s) 3-7, 9-13 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/or papers	vn from consideration.	
9)[] -	The specification is objected to by the Examine	r	
10) 🗀 -	The drawing(s) filed on is/are: a) accomplicant may not request that any objection to the Replacement drawing sheet(s) including the correct of the oath or declaration is objected to by the Explacement drawing sheet(s) including the correct of the oath or declaration is objected to by the Explanation is objected to be accomplished to the control of the	epted or b) objected to by the drawing(s) be held in abeyance. Se ion is required if the drawing(s) is ob	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).
Priority u	nder 35 U.S.C. § 119		
12)	Acknowledgment is made of a claim for foreign All b) Some * c) None of:  1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priority documents application from the International Bureau ee the attached detailed Office action for a list	s have been received. s have been received in Applicat rity documents have been receive u (PCT Rule 17.2(a)).	ion No ed in this National Stage
Attachment	(s) e of References Cited (PTO-892)	4) 🔲 Interview Summary	· (PTO-413)
2) D Notice 3) D Inform	e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) No(s)/Mail Date	Paper No(s)/Mail D	

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### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 2. Claim 10 is rejected under 35 U.S.C. 102(e) as being anticipated by Ying et al. (US 2003/0176073).

Ying describes a method for forming a ferroelectric capacitor comprising: providing a dielectric oxide layer on the substrate 210 (paragraph [0016]); forming a barrier 220 over the dielectric layer (paragraph [0017]); providing a first metal Ir layer 230, a ferroelectric PZT layer 240 and a second Ir metal layer 250 in the order respectively (paragraphs [0018,0019]); forming a TiAlN hardmask over the Ir layer 250 (paragraph [0020]), etching the second Ir layer, the ferroelectric layer, and the first Ir layer using a plasma process at a T about 250-450 degrees C (paragraph [0028]). Wherein the sidewalls of the capacitor have an angle of greater than about 80 degrees (paragraph [0015]).

## Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person

having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

4. Claims 3-7, 9, 11-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ying as applied to claim 10 above, and further in view of Moise et al. (US 6,211,035).

Ying describes etching the Ir layers using Cl2/O2/N2 and the PZT using Cl2/O2 (table 1). Unlike claimed invention, he doesn't describe the Ir etchant includes CO and the PZT etchant includes BCl3. Moise describes an etching method of Ir and PZT layers wherein he teaches the Cl2 and O2 sources can have BCl3 in addition to the Cl2 and CO in addition to O2 (col. 18, line 65-col. 19, line 13). It would have been obvious for one skilled in the art, in light of Moise, that BCl3 and CO can be added to the etchant of the Ir and PZT layers as a source of Cl2 and O2 to etch the Ir and the PZT layers with a reasonable expectation of success.

Referring to claims 3, 6, and 12, applied prior art of Moise doesn't describe the gases ratios of BCl3 and Cl2 are from 1:4-10:1. However, one skilled in the art would find it obvious to determine the gases ratios from the routine experimentation in order to provide optimum ratios of etching gases including BCl3 and Cl2 to etch the PZT layer with a reasonable expectation of success.

### Response to Arguments

5. Applicant's arguments filed 1/10/06 have been fully considered but they are not persuasive.

Applicant's argument that the cited ratio range of the present is not recognized by the cited art as a result-effective variable because they don't indicate that a ratio range may impact the sidewall profile of the capacitor stack is found unpersuasive because it is not necessary to show that a ratio range may impact the sidewall profile of the capacitor stack in order to

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recognize that the ratio range is a result-effective variable. It would be within one skilled in the art to recognize that any processing parameter is a result-effective variable, especially the concentration of an etchant. It would be obvious to one skilled in the art that changing the concentration of the etchant would certainly change the etch rate. Therefore, one skilled in the art at the time of the invention would find it obvious to determine the ratio or concentration of the etchant through test runs in order to provide an optimum range to etch the PZT.

Referring to applicant's argument that Ying does not teach forming sidewalls having angle between 78 and 88 degree. Please see paragraph [0015] where he teaches the sidewalls angle is about 80 degree, which would certain an angle between 78 and 88 degree.

#### Conclusion

6. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to DuyVu n. Deo whose telephone number is 571-272-1462.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on 571-272-1465. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Primary Examiner Duy-Vu N. Deo 3/9/06